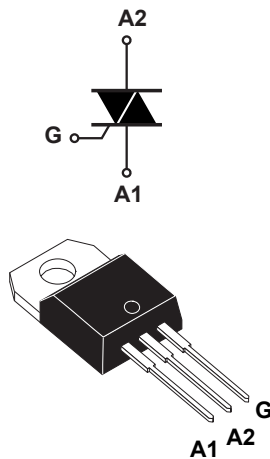


## 12 A - 800 V - 150 °C 8H Triac in TO-220AB insulated



TO-220AB insulated

### Features

- 12 A medium current Triac
- 800 V symmetrical blocking voltage
- 150 °C maximum junction temperature  $T_j$
- Three triggering quadrants
- High noise immunity - static  $dV/dt$
- Robust dynamic turn-off commutation -  $(di/dt)_c$
- ECOPACK2 compliant component
- Molding resin UL94-V0 flammability certified
- UL recognized for insulation , UL1557: 2.5 kV
  - Reference file: E81734

### Applications

- General purpose AC line load control
- AC induction and universal motor control
- Lighting and automation I/O control
- Water heater, room heater and coffee machine
- Home automation smart AC plug
- Inrush current limiter in AC DC rectifiers

### Description

Specifically designed to operate at 800 V and 150 °C, the **T1235H-8I** Triac housed in TO-220AB insulated provides an enhanced thermal management: this 12 A Triac is the right choice for a compact drive of AC loads and enables the heatsink size reduction.

Based on the ST high temperature Snubberless technology, it offers higher specified turn off commutation and noise immunity levels up to the  $T_j$  max.

Snubberless is a trademark of STMicroelectronics.

The **T1235H-8I** safely optimizes the control of the motors and heaters loads for the most constraining environments of home appliances and industrial control.

By using an internal ceramic pad, it provides a recognized voltage insulation, rated at 2500  $V_{RMS}$ .

#### Product status link

[T1235H-8I](#)

#### Product summary

$I_{T(RMS)}$	12 A
$V_{DRM}/V_{RRM}$	800 V
$V_{DSM}/V_{RSM}$	900 V
$I_{GT}$	35 mA
$T_j$ max.	150 °C

# 1 Characteristics

**Table 1. Absolute maximum ratings (limiting values)**

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	$T_c = 122\text{ }^\circ\text{C}$	12	A
$I_{TSM}$	Non repetitive surge peak on-state current (full cycle, $T_j$ initial = $25\text{ }^\circ\text{C}$ )	$t = 16.7\text{ ms}$	126	A
		$t = 20\text{ ms}$	120	
$I^2t$	$I^2t$ value for fusing	$t_p = 10\text{ ms}$	95	$\text{A}^2\text{s}$
$di/dt$	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$ , $t_r \leq 100\text{ ns}$ , $f = 100\text{ Hz}$	$T_j = 25\text{ }^\circ\text{C}$	100	$\text{A}/\mu\text{s}$
$V_{DRM}/V_{RRM}$	Repetitive peak off-state voltage		800	V
$V_{DSM}/V_{RSM}$	Non Repetitive peak off-state voltage	$t_p = 10\text{ ms}$ , $T_j = 25\text{ }^\circ\text{C}$	900	V
$I_{GM}$	Peak gate current	$t_p = 20\text{ }\mu\text{s}$ , $T_j = 150\text{ }^\circ\text{C}$	4	A
$P_{GM}$	Maximum gate power dissipation		5	W
$P_{G(AV)}$	Average gate power dissipation	$T_j = 150\text{ }^\circ\text{C}$	1	W
$T_{stg}$	Storage temperature range		-40 to +150	$^\circ\text{C}$
$T_j$	Operating junction temperature range		-40 to +150	$^\circ\text{C}$
$T_L$	Maximum lead temperature for soldering during 10 s		260	$^\circ\text{C}$
$V_{INS}$	Insulation RMS voltage, 1 minute		2.5	kV

**Table 2. Electrical characteristics ( $T_j = 25\text{ }^\circ\text{C}$ , unless otherwise specified)**

Symbol	Test conditions		Quadrants		Value	Unit
$I_{GT}$	$V_D = 12\text{ V}$ , $R_L = 30\text{ }\Omega$		I - II - III	Min.	5	mA
				Max.	35	mA
$V_{GT}$	$V_D = 12\text{ V}$ , $R_L = 30\text{ }\Omega$		I - II - III	Max.	1.3	V
$V_{GD}$	$V_D = V_{DRM}$ , $R_L = 3.3\text{ k}\Omega$	$T_j = 150\text{ }^\circ\text{C}$	I - II - III	Min.	0.15	V
$I_L$	$I_G = 1.2 \times I_{GT}$		I - III	Max.	50	mA
			II	Max.	80	mA
$I_H^{(1)}$	$I_T = 500\text{ mA}$ , gate open			Max.	35	mA
$dV/dt^{(1)}$	$V_D = V_R = 536\text{ V}$ , gate open		$T_j = 150\text{ }^\circ\text{C}$	Min.	2000	$\text{V}/\mu\text{s}$
$(di/dt)_c^{(1)}$	Without snubber network		$T_j = 150\text{ }^\circ\text{C}$	Min.	12	$\text{A}/\text{ms}$

1. For both polarities of A2 referenced to A1.

**Table 3. Static characteristics**

Symbol	Test conditions	$T_j$		Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 17\text{ A}$ , $t_p = 380\ \mu\text{s}$	25 °C	Max.	1.50	V
$V_{TO}^{(1)}$	Threshold voltage	150 °C	Max.	0.80	V
$R_D^{(1)}$	Dynamic resistance	150 °C	Max.	32	m $\Omega$
$I_{DRM}/I_{RRM}$	$V_D = V_R = V_{DRM} = V_{RRM}$	25 °C	Max.	2.0	$\mu\text{A}$
		150 °C		4.5	mA
	$V_D = V_R = 400\text{ V}$ , peak voltage	150 °C	Max.	1.7	mA

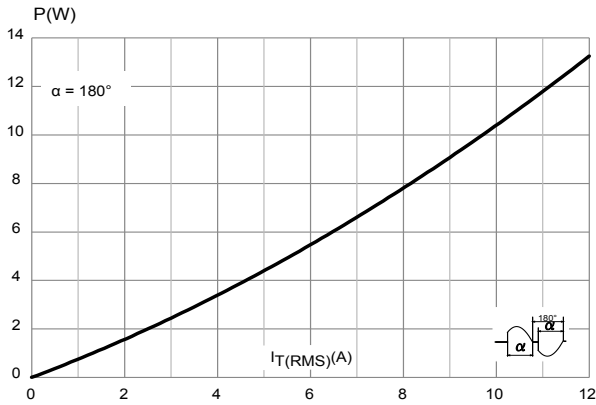
1. For both polarities of A2 referenced to A1.

**Table 4. Thermal resistance**

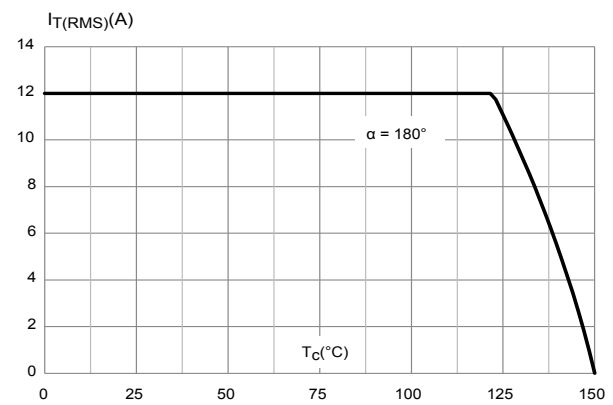
Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	Max.	2.1	°C/W
$R_{th(j-a)}$	Junction to ambient	Typ.	60	°C/W

### 1.1 Characteristics (curves)

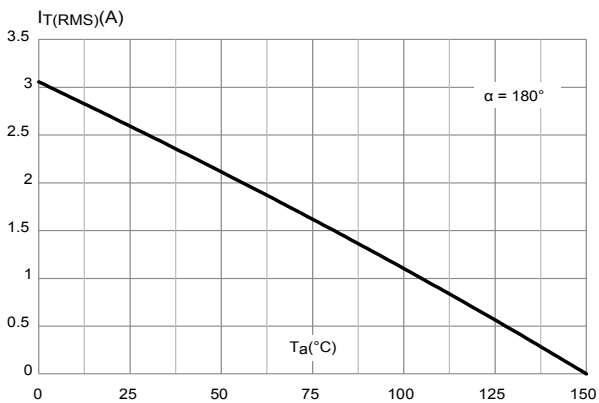
**Figure 1. Maximum power dissipation versus on-state RMS current (full cycle)**



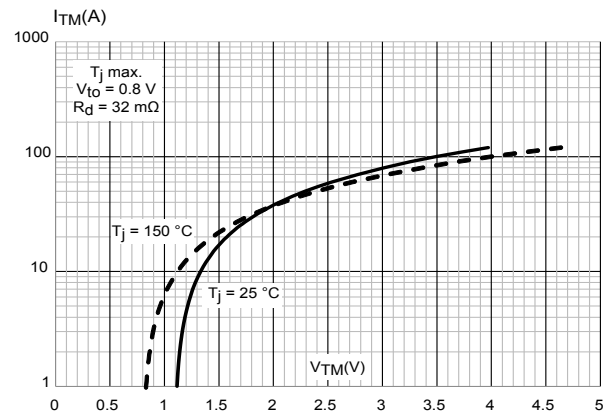
**Figure 2. On-state RMS current versus case temperature (full cycle)**



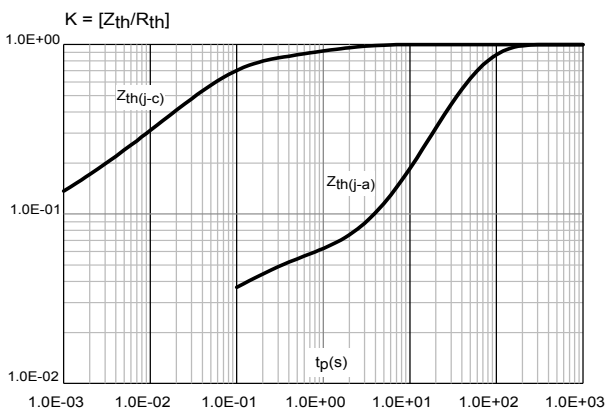
**Figure 3. On-state RMS current versus ambient temperature (free air convection)**



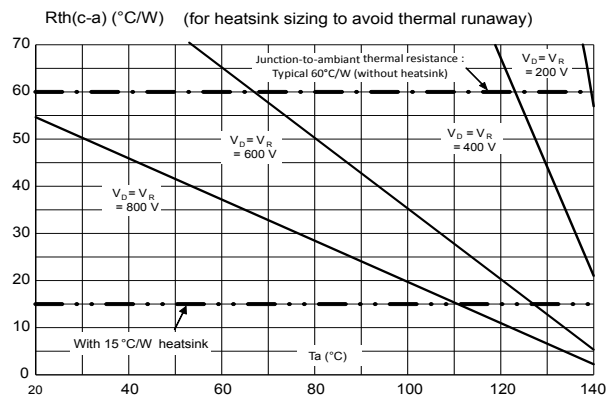
**Figure 4. On-state characteristics (maximum values)**



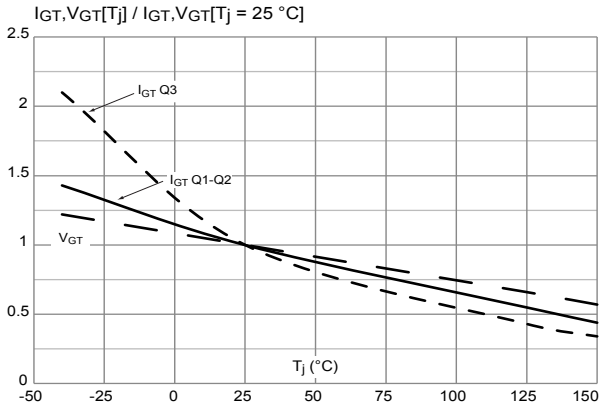
**Figure 5. Relative variation of thermal impedance versus pulse duration**



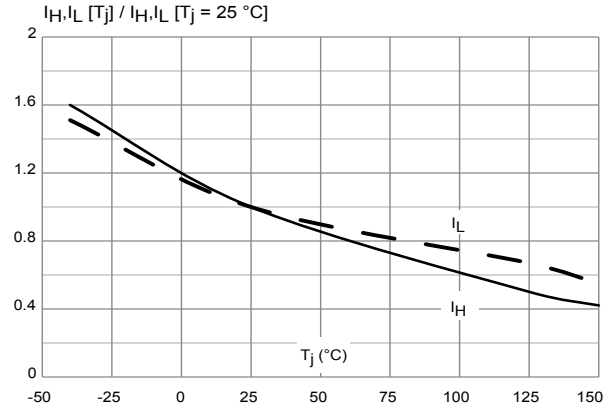
**Figure 6. Recommended maximum case-to-ambient thermal resistance versus ambient temperature for different peak off-state voltages**



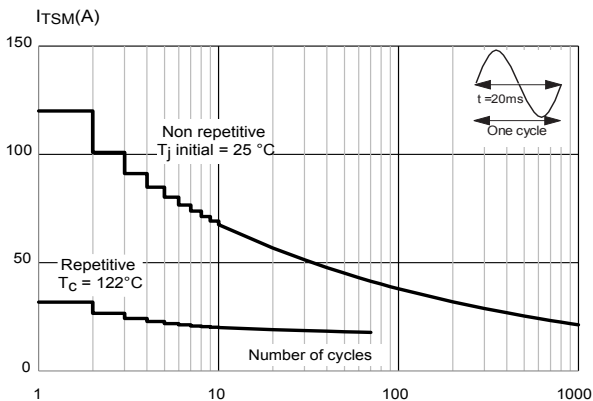
**Figure 7. Relative variation of gate trigger voltage and current versus junction temperature (typical values)**



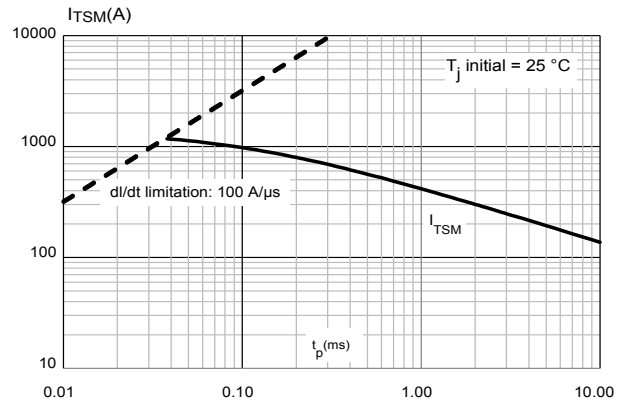
**Figure 8. Relative variation of holding current and latching current versus junction temperature (typical values)**



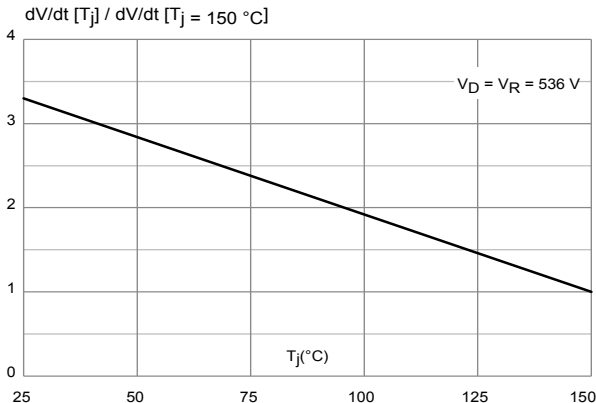
**Figure 9. Surge peak on-state current versus number of cycles**



**Figure 10. Non repetitive surge peak on-state current for a sinusoidal pulse with width  $t_p < 10$  ms**



**Figure 11. Relative variation of static dV/dt immunity versus junction temperature**



**Figure 12. Relative variation of critical rate of decrease of main current versus junction temperature**

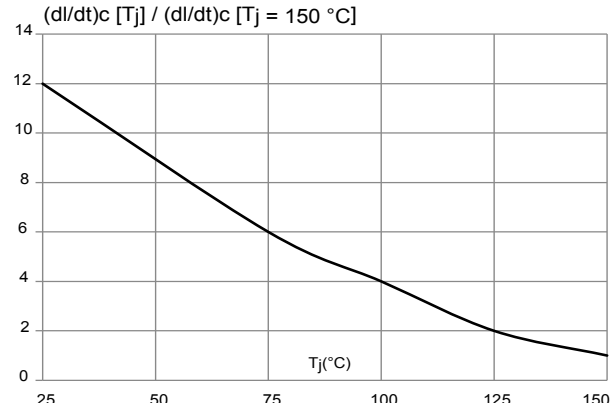
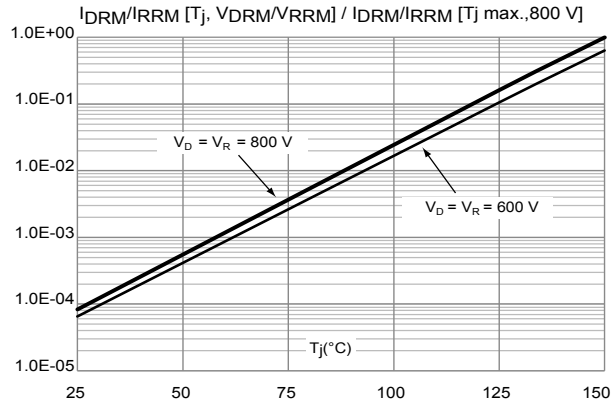


Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage



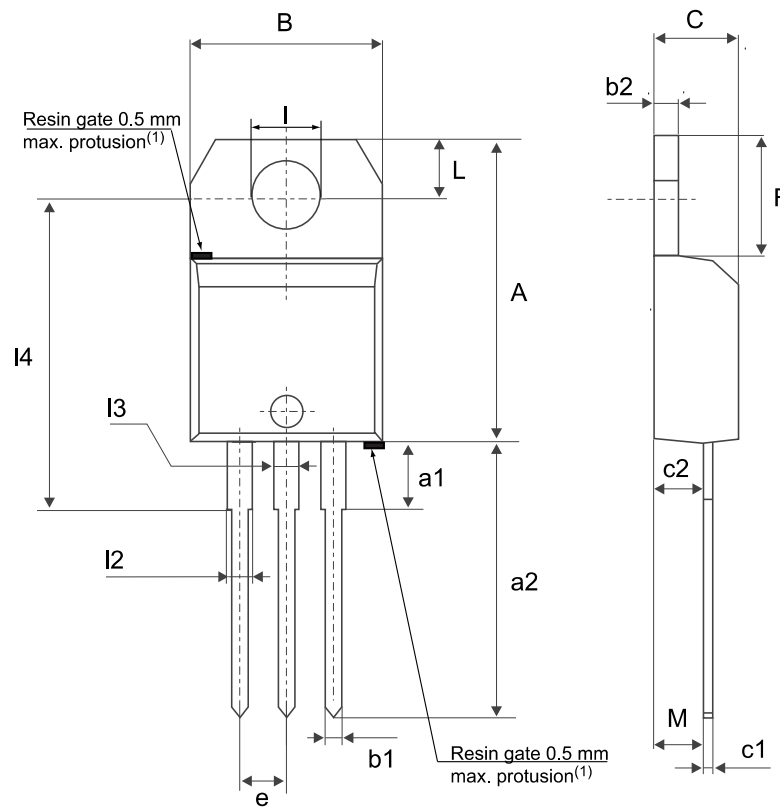
## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 2.1 TO-220AB insulated package information

- Molding compound resin is halogen free and meets UL94 flammability standard, level V0
- Lead-free plating package leads
- Recommended torque: 0.4 to 0.6 N·m

Figure 14. TO-220AB package outline



(1)Resin gate position accepted in one of the two positions or in the symmetrical opposites.

**Table 5. TO-220AB package mechanical data**

Ref.	Dimensions					
	Millimeters			Inches <sup>(1)</sup>		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
I	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
I2	1.14		1.70	0.0449		0.0669
I3	1.14		1.70	0.0449		0.0669
I4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

1. Inch dimensions are for reference only.



### 3 Ordering information

Figure 15. Ordering information scheme

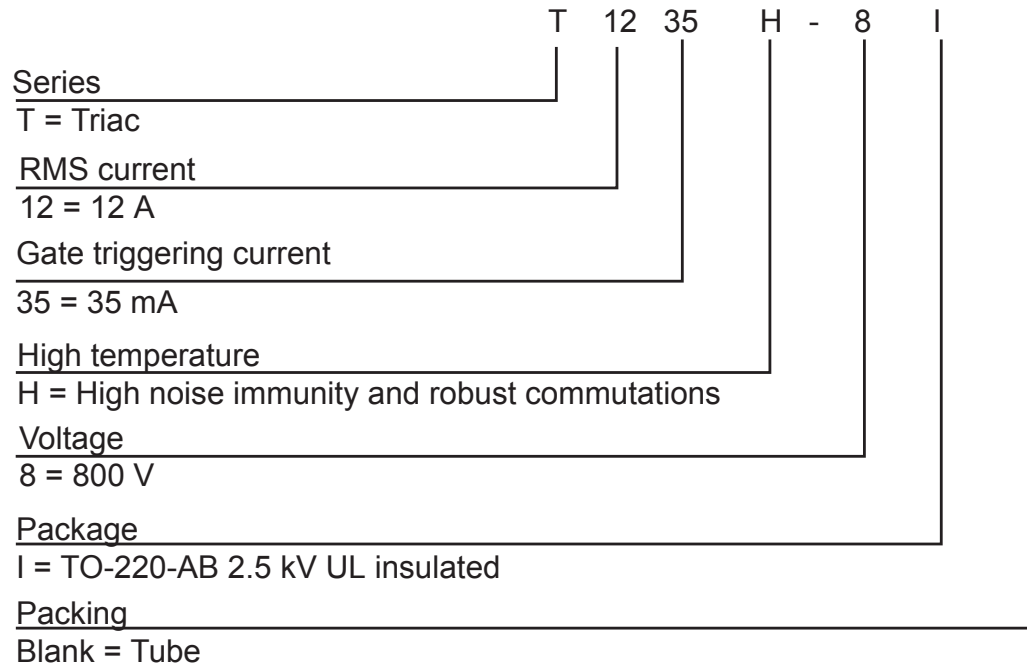


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T1235H-8I	T1235H-8I	TO-220AB Ins.	2.3 g	50	Tube

## Revision history

**Table 7. Document revision history**

Date	Version	Changes
20-Nov-2020	1	Initial release.
11-Dec-2020	2	Updated general description.

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